



BUK6607-75C

N-channel TrenchMOS FET

Rev. 2 — 17 November 2010

Product data sheet

1. Product profile

1.1 General description

Intermediate level gate drive N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using advanced TrenchMOS technology. This product has been designed and qualified to the appropriate AEC Q101 standard for use in high performance automotive applications.

1.2 Features and benefits

- AEC Q101 compliant
- Suitable for intermediate level gate drive sources
- Suitable for thermally demanding environments due to 175 °C rating

1.3 Applications

- 12 V and 24 V Automotive systems
- Electric and electro-hydraulic power steering
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$	-	-	75	V
I_D	drain current	$V_{GS} = 10\text{ V}$; $T_{mb} = 25^\circ\text{C}$; see Figure 1	[1]	-	100	A
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; see Figure 2	-	-	204	W
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10\text{ V}$; $I_D = 25\text{ A}$; $T_j = 25^\circ\text{C}$; see Figure 11	-	6	7	$\text{m}\Omega$

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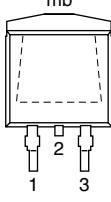
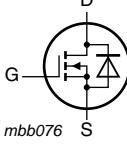
Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 100 \text{ A}$; $V_{sup} \leq 75 \text{ V}$; $R_{GS} = 50 \Omega$; $V_{GS} = 10 \text{ V}$; $T_{j(init)} = 25 \text{ }^\circ\text{C}$; unclamped	-	-	191	mJ
Dynamic characteristics						
Q_{GD}	gate-drain charge	$I_D = 25 \text{ A}$; $V_{DS} = 60 \text{ V}$; $V_{GS} = 10 \text{ V}$; see Figure 13 ; see Figure 14	-	35	-	nC

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	Drain		
3	S	source		
mb	D	mounting base; connected to drain		
SOT404 (D2PAK)				

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BUK6607-75C	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}; T_j \leq 175^\circ\text{C}$	-	75	V
V_{GS}	gate-source voltage	DC	[1]	-16	V
		Pulsed		-20	V
I_D	drain current	$T_{mb} = 25^\circ\text{C}; V_{GS} = 10\text{ V}$; see Figure 1	[3]	-	A
		$T_{mb} = 100^\circ\text{C}; V_{GS} = 10\text{ V}$; see Figure 1		-	A
I_{DM}	peak drain current	$T_{mb} = 25^\circ\text{C}; t_p \leq 10\ \mu\text{s}$; pulsed; see Figure 3	-	423	A
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; see Figure 2	-	204	W
T_{stg}	storage temperature		-55	175	°C
T_j	junction temperature		-55	175	°C
Source-drain diode					
I_S	source current	$T_{mb} = 25^\circ\text{C}$	[3]	-	A
I_{SM}	peak source current	$t_p \leq 10\ \mu\text{s}$; pulsed; $T_{mb} = 25^\circ\text{C}$		-	A
Avalanche ruggedness					
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 100\text{ A}; V_{sup} \leq 75\text{ V}; R_{GS} = 50\ \Omega$; $V_{GS} = 10\text{ V}; T_{j(init)} = 25^\circ\text{C}$; unclamped	-	191	mJ
$E_{DS(AL)R}$	repetitive drain-source avalanche energy		[4][5][6]	-	J

[1] -16 V accumulated duration not to exceed 168 hrs.

[2] Accumulated pulse duration not to exceed 5mins.

[3] Continuous current is limited by package.

[4] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[5] Repetitive avalanche rating limited by an average junction temperature of 170 °C.

[6] Refer to application note AN10273 for further information.

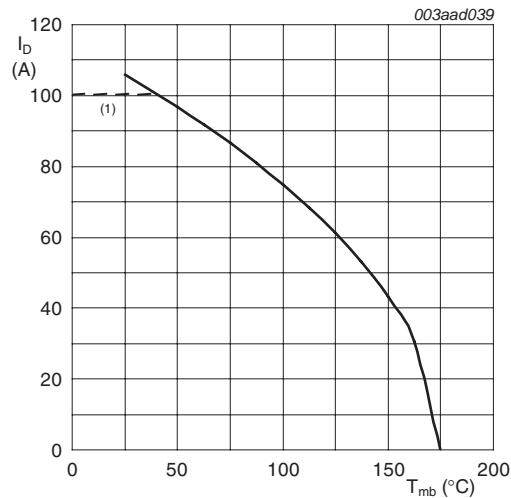
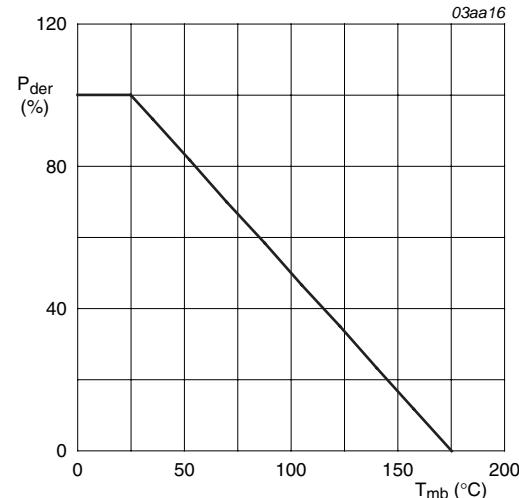
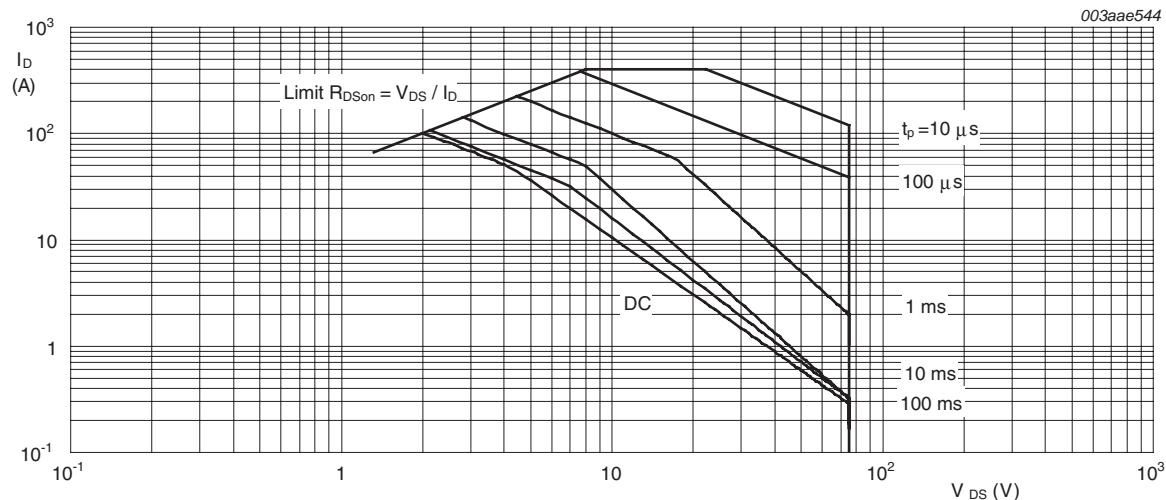


Fig 1. Continuous drain current as a function of mounting base temperature.



$$P_{der} = \frac{P_{tot}}{P_{tot}(25^{\circ}\text{C})} \times 100 \%$$

Fig 2. Normalized total power dissipation as a function of mounting base temperature



$T_{mb} = 25^{\circ}\text{C}$; I_{DM} is a single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j\text{-mb})}$	thermal resistance from junction to mounting base	see Figure 4	-	-	0.74	K/W

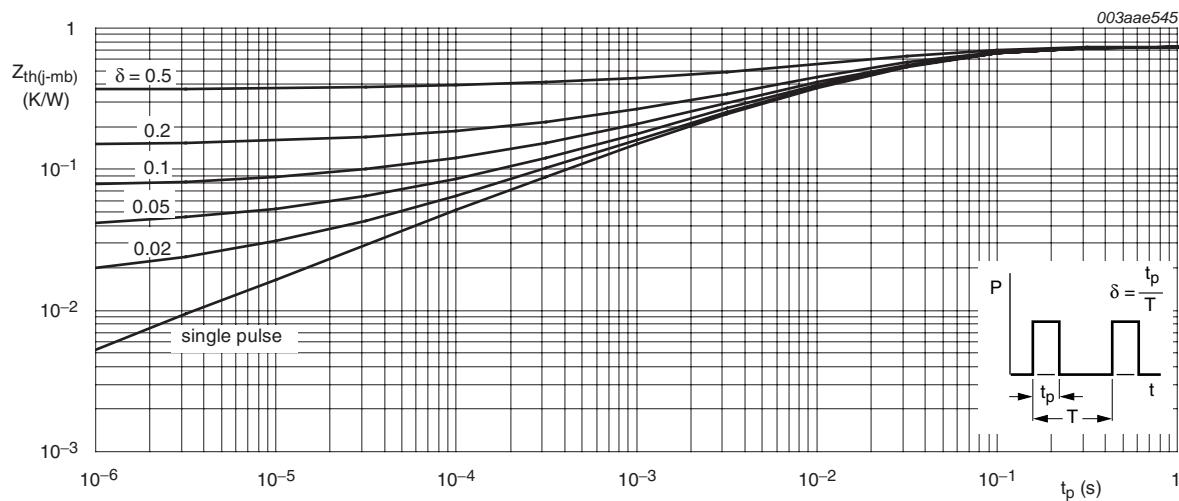


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

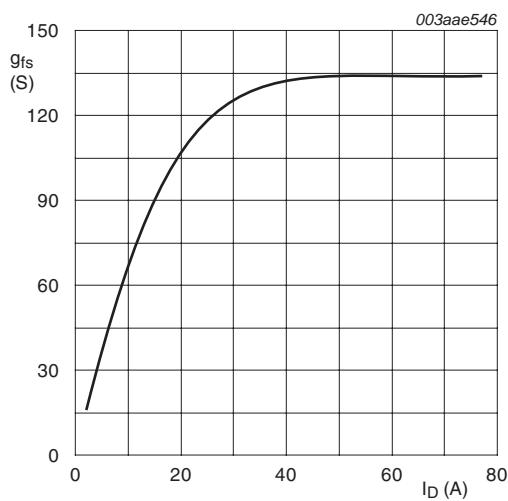
6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$ $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$	75	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25^\circ C$; see Figure 9 ; see Figure 10 $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55^\circ C$; see Figure 10 $I_D = 2.5 \text{ mA}; V_{DS} = V_{GS}; T_j = 175^\circ C$; see Figure 10	1.8	2.3	2.8	V
I_{DSS}	drain leakage current	$V_{DS} = 75 V; V_{GS} = 0 V; T_j = 175^\circ C$ $V_{DS} = 75 V; V_{GS} = 0 V; T_j = 25^\circ C$	-	-	500	μA
I_{GSS}	gate leakage current	$V_{DS} = 0 V; V_{GS} = 20 V; T_j = 25^\circ C$ $V_{DS} = 0 V; V_{GS} = -20 V; T_j = 25^\circ C$	-	2	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C$; see Figure 11 $V_{GS} = 4.5 V; I_D = 25 A; T_j = 25^\circ C$; see Figure 11 $V_{GS} = 5 V; I_D = 25 A; T_j = 25^\circ C$; see Figure 11 $V_{GS} = 10 V; I_D = 25 A; T_j = 175^\circ C$; see Figure 12 ; see Figure 11	-	6	7	$m\Omega$
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 25 A; V_{DS} = 60 V; V_{GS} = 10 V$; see Figure 13 ; see Figure 14 $I_D = 25 A; V_{DS} = 60 V; V_{GS} = 5 V$; see Figure 13 ; see Figure 14	-	123	-	nC
Q_{GS}	gate-source charge	$I_D = 25 A; V_{DS} = 60 V; V_{GS} = 10 V$; see Figure 13 ; see Figure 14	-	15	-	nC
Q_{GD}	gate-drain charge	see Figure 13 ; see Figure 14	-	35	-	nC
C_{iss}	input capacitance	$V_{GS} = 0 V; V_{DS} = 25 V; f = 1 \text{ MHz}$	-	5610	7600	pF
C_{oss}	output capacitance	$T_j = 25^\circ C$; see Figure 15	-	441	530	pF
C_{rss}	reverse transfer capacitance		-	297	410	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 55 V; R_L = 2.2 \Omega; V_{GS} = 10 V$	-	24	-	ns
t_r	rise time	$R_{G(ext)} = 10 \Omega$	-	54	-	ns
$t_{d(off)}$	turn-off delay time		-	247	-	ns
t_f	fall time		-	110	-	ns
L_D	internal drain inductance	from upper edge of drain mounting base to centre of die; $T_j = 25^\circ C$	-	3.5	-	nH
L_S	internal source inductance	from source lead to source bond pad; $T_j = 25^\circ C$	-	7.5	-	nH

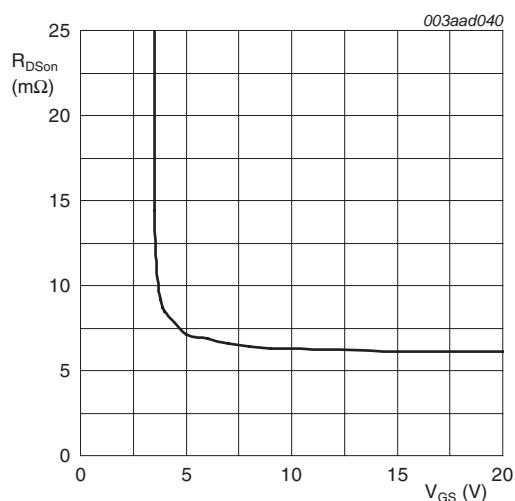
Table 6. Characteristics ...continued

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Source-drain diode						
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; see Figure 16	-	0.8	1.2	V
t_{rr}	reverse recovery time	$I_S = 20 \text{ A}$; $dI_S/dt = -100 \text{ A}/\mu\text{s}$; $V_{GS} = 0 \text{ V}$	-	54	-	ns
Q_r	recovered charge	$V_{DS} = 25 \text{ V}$	-	129	-	nC



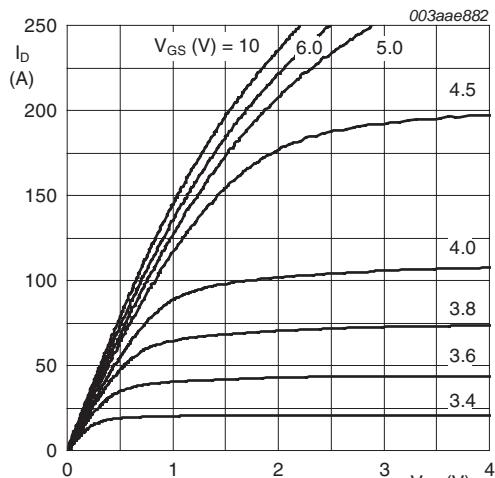
$T_j = 25 \text{ }^\circ\text{C}$; $V_{DS} = 25 \text{ V}$

Fig 5. Forward transconductance as a function of drain current; typical values



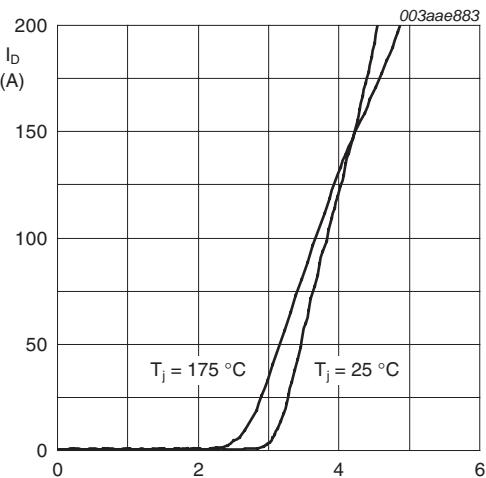
$T_j = 25 \text{ }^\circ\text{C}$; $I_D = 25 \text{ A}$

Fig 6. Drain-source on-state resistance as a function of gate-source voltage; typical values



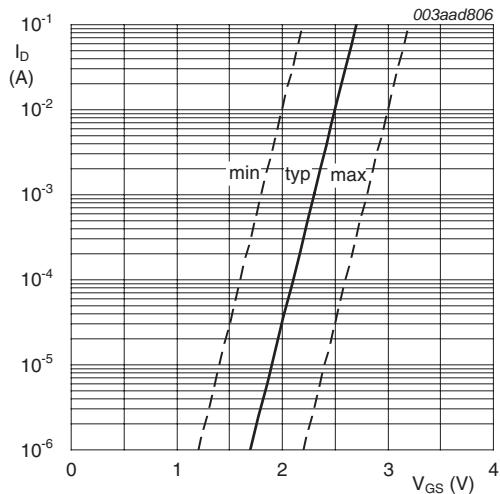
$T_j = 25 \text{ }^\circ\text{C}$

Fig 7. Output characteristics: drain current as a function of drain-source voltage; typical values



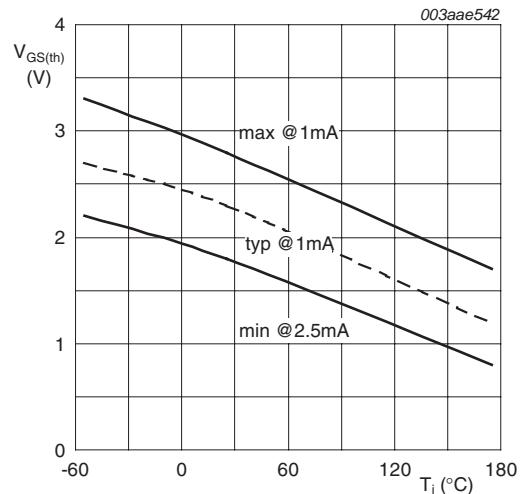
$V_{DS} > I_D \times R_{DSon}$

Fig 8. Transfer characteristics: drain current as a function of gate-source voltage; typical values



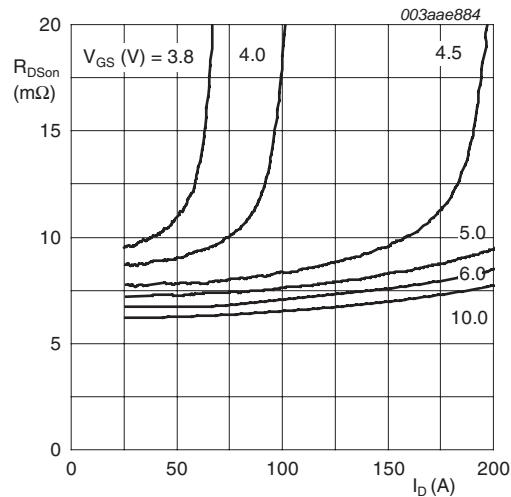
$T_j = 25^\circ\text{C}; V_{DS} = 5\text{V}$

Fig 9. Sub-threshold drain current as a function of gate-source voltage



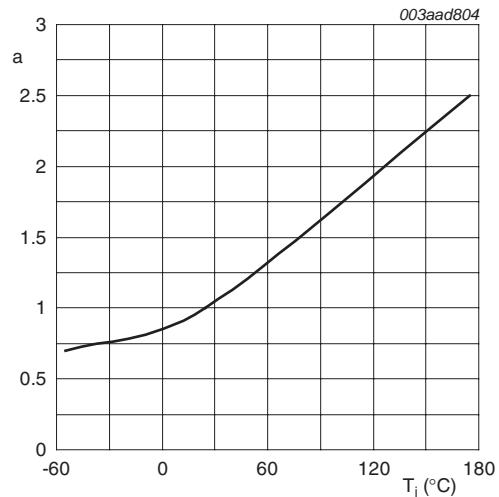
$I_D = 1\text{mA}; V_{DS} = V_{GS}$

Fig 10. Gate-source threshold voltage as a function of junction temperature



$T_j = 25^\circ\text{C}$

Fig 11. Drain-source on-state resistance as a function of drain current; typical values



$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ\text{C})}$$

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature

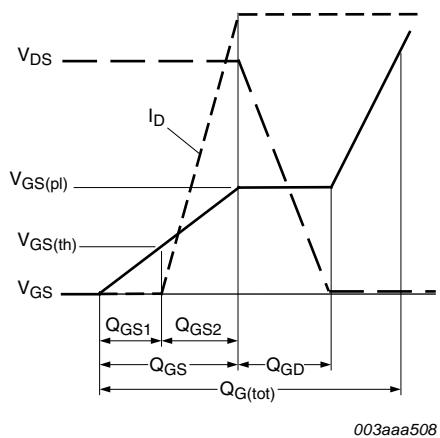


Fig 13. Gate charge waveform definitions

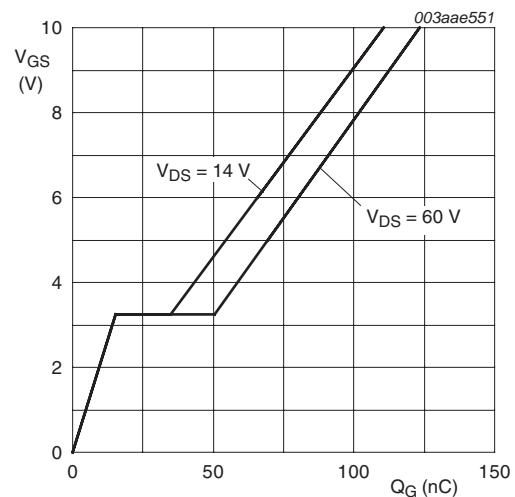


Fig 14. Gate-source voltage as a function of gate charge; typical values

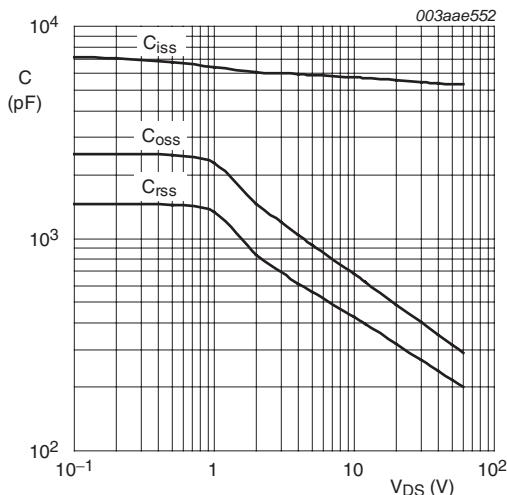


Fig 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

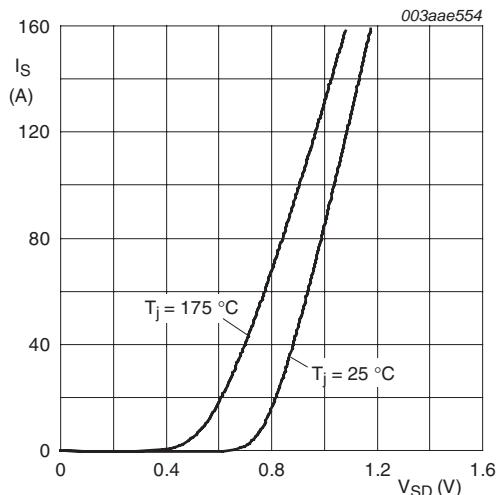
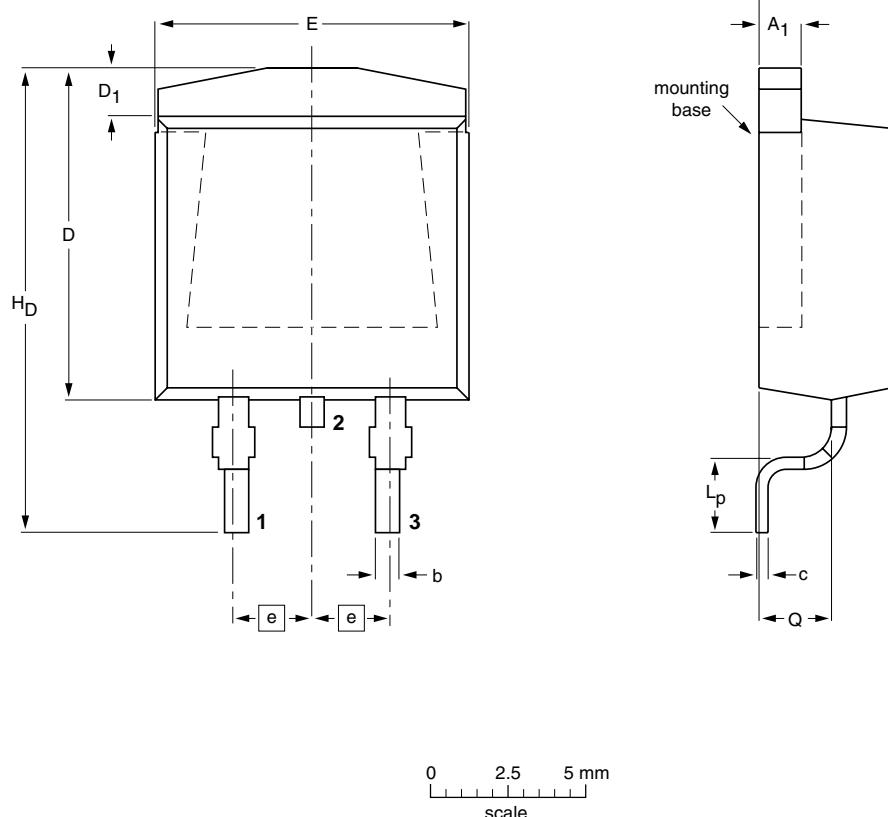


Fig 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

7. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)

SOT404



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	c	D _{max.}	D ₁	E	e	L _p	H _D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT404						05-02-11 06-03-16

Fig 17. Package outline SOT404 (D2PAK)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK6607-75C v.2	20101117	Product data sheet	-	BUK6607-75C v.1
Modifications:		<ul style="list-style-type: none">• Status changed from objective to product.		
BUK6607-75C v.1	20090323	Objective data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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